

MSD42SWT1G

NPN Silicon General Purpose High Voltage Transistor

This NPN Silicon Planar Transistor is designed for general purpose amplifier applications. This device is housed in the SC-70/SOT-323 package which is designed for low power surface mount applications.

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	300	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	300	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	6.0	Vdc
Collector Current - Continuous	I _C	150	mAdc

THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation (Note 1)	P _D	150	mW
Junction Temperature	T _J	150	°C
Storage Temperature Range	T _{stg}	- 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

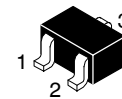
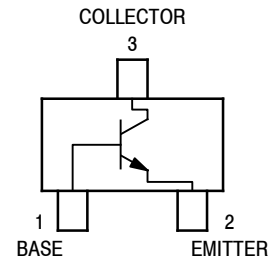
Characteristic	Symbol	Min	Max	Unit
Collector-Emitter Breakdown Voltage (I _C = 1.0 mAdc, I _B = 0)	V _{(BR)CEO}	300	-	Vdc
Collector-Base Breakdown Voltage (I _C = 100 µAdc, I _E = 0)	V _{(BR)CBO}	300	-	Vdc
Emitter-Base Breakdown Voltage (I _E = 100 µAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Collector-Base Cutoff Current (V _{CB} = 300 Vdc, I _E = 0)	I _{CBO}	-	0.1	µA
Emitter-Base Cutoff Current (V _{EB} = 6.0 Vdc, I _B = 0)	I _{EBO}	-	0.1	µA
DC Current Gain (Note 2) (V _{CE} = 10 Vdc, I _C = 1.0 mAdc) (V _{CE} = 10 Vdc, I _C = 30 mAdc)	h _{FE1} h _{FE2}	25 40	200 -	-
Collector-Emitter Saturation Voltage (Note 2) (I _C = 200 mAdc, I _B = 2.0 mAdc)	V _{CE(sat)}	-	0.5	Vdc

1. Device mounted on a FR-4 glass epoxy printed circuit board using the minimum recommended footprint.
2. Pulse Test: Pulse Width ≤ 300 µs, D.C. ≤ 2%.



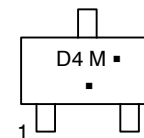
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SC-70 (SOT-323)
CASE 419
STYLE 3

MARKING DIAGRAM



D4 = Device Code
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

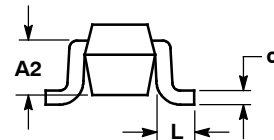
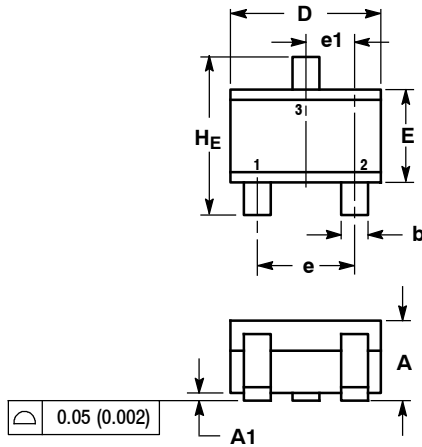
Device	Package	Shipping†
MSD42SWT1G	SC-70/SOT-323 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MSD42SWT1G

PACKAGE DIMENSIONS

SC-70 (SOT-323)
CASE 419-04
ISSUE N



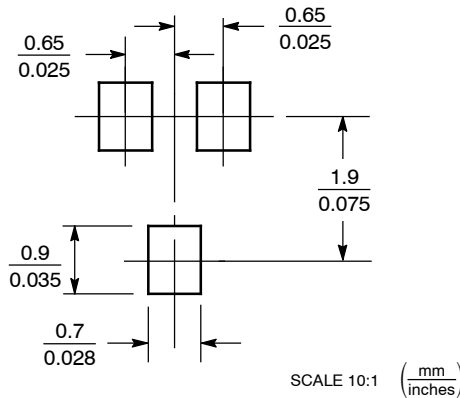
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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